Electrical Characteristics	T <sub>a</sub> =25°C unless otherwise noted
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Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage : BC307	I <sub>C</sub> = -2mA, I <sub>B</sub> =0	-45			V
	: BC308/309		-25			V
$BV_{CES}$	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -10μA, V <sub>BE</sub> =0	50			.,
	: BC307 : BC308/309		-50 -30			V V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_{E} = -10\mu A, I_{C} = 0$	-5			V
I <sub>CES</sub>	Collector Cut-off Current					
CES	: BC307	V <sub>CF</sub> = -45V, V <sub>BF</sub> =0		-2	-15	nA
	: BC308/309	V <sub>CE</sub> = -25V, V <sub>BE</sub> =0		-2	-15	nA
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> = -5V, I <sub>C</sub> = -2mA	120		800	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -10mA, I <sub>B</sub> = -0.5mA			-0.3	V
		I <sub>C</sub> = -100mA, I <sub>B</sub> = -5mA		-0.5		V
V <sub>BE</sub> (sat)	Collector-Base Saturation Voltage	I <sub>C</sub> = -10mA, I <sub>B</sub> = -0.5mA		-0.7		V
		$I_{C}$ = -100mA, $I_{B}$ = -5mA		-0.85		V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	$V_{CE}$ = -5V, $I_{C}$ = -2mA	-0.55	-0.62	-0.7	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> = -5V, I <sub>C</sub> = -10mA, f=50MHz		130		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = -10V, I <sub>E</sub> =0, f=1MHz			6	pF
C <sub>ib</sub>	Input Capacitance	V <sub>EB</sub> = -0.5V, I <sub>C</sub> =0, f=1MHz		12		pF
NF	Noise Figure					
	: BC307/308	$V_{CE} = -5V, I_{C} = -0.2mA,$			10	dB
	: BC309	R <sub>G</sub> =2KΩ, f=1KHz			4	dB
	: BC309	V <sub>CE</sub> = -5V, I <sub>C</sub> = -0.2mA		2	4	dB
		$R_G=2K\Omega$ , f=30~15KHz			İ	

# h<sub>FE</sub> Classification

Classification	А	В	С
h <sub>FE</sub>	120 ~ 220	180 ~ 460	380 ~ 800

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## **Typical Characteristics**

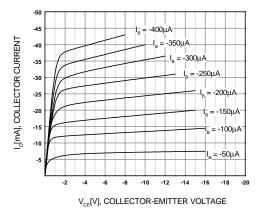


Figure 1. Static Characteristic

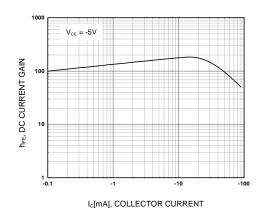


Figure 2. DC current Gain

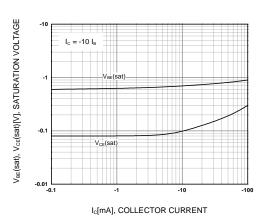


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

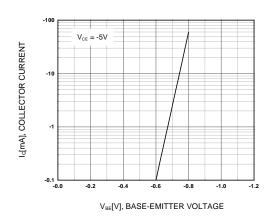


Figure 4. Base-Emitter Capacitance

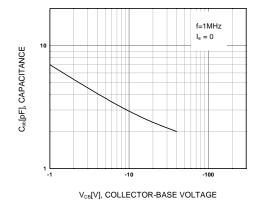


Figure 5. Collector Output Capacitance

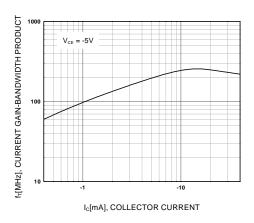
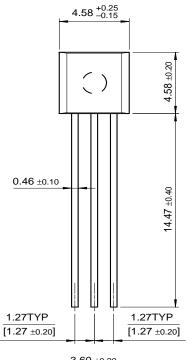


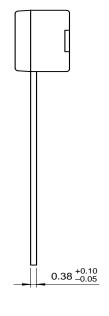
Figure 6. Current Gain Bandwidth Product

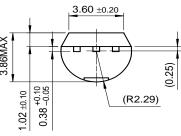
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## **Package Dimensions**

## TO-92







Dimensions in Millimeters

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CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
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EnSigna™	$I^2C^{TM}$	$OCX^{TM}$	RapidConfigure™	UHC™
Across the board.	. Around the world.™	OCXPro™	RapidConnect™	UltraFET <sup>®</sup>
The Power Franc	hise™	OPTOLOGIC <sup>®</sup>	SILENT SWITCHER®	$VCX^{TM}$
Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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